General Specifications



The AVX MM series is a multi-layer ceramic capacitor designed for use in medical applications other than implantable/life support. These components have the design & change control expected for medical devices and also offer enhanced LAT including reliability testing and 100% inspection.

APPLICATIONS

Implantable, Non-Life Supporting Medical Devices

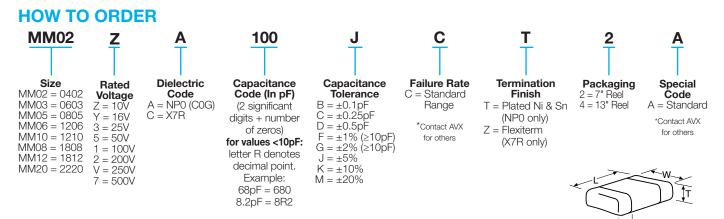
• e.g. implanted temporary cardiac monitor, insulin pumps

External, Life Supporting Medical Devices

• e.g. heart pump external controller

External Devices

• e.g. patient monitoring, diagnostic equipment



COMMERCIAL VS MM SERIES PROCESS COMPARISON

	Commercial	MM Series
Administrative	Standard part numbers; no restriction on who purchases these parts	Specific series part number, used to control supply of product
Design	Minimum ceramic thickness of 0.020" on all X7R product	Minimum ceramic thickness of 0.029" (0.74mm)
Dicing	Side & end margins = 0.003" min	Side & end margins = 0.004" min Cover layers = 0.003" min
Lot Qualification Destructive Physical Analysis (DPA)	As per EIA RS469	Increased sample plan – stricter criteria
Visual/Cosmetic Quality	Standard process and inspection	100% inspection
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing
Design/Change Control	Required to inform customer of changes in: • form • fit • function	AVX will qualify and notify customers before making any change to the following materials or processes: • Dielectric formulation, type, or supplier • Metal formulation, type, or supplier • Termination material formulation, type, or supplier • Manufacturing equipment type • Quality testing regime including sample size and accept/ reject criteria

NP0 (C0G) - Specifications & Test Methods

Parame	ter/Test	NP0 Specification Limits	Measuring	Conditions								
	perature Range	-55°C to +125°C	Temperature C									
Capac	itance	Within specified tolerance	Freq.: 1.0 MHz ± 109									
Q Insulation Resistance		<30 pF: Q≥ 400+20 x Cap Value		% for cap > 1000 pF								
	<i>A</i>	≥30 pF: Q≥ 1000	Voltage: 1.0									
Inculation	Resistance	100,000M Ω or 1000M Ω - μF,	Charge device with rated voltage for									
Ilisulation	i lesistarice	whichever is less	60 ± 5 secs @ roo									
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.									
	Appearance	No defects	Deflectio									
	Capacitance		Test Time: 3									
Resistance to	Variation	±5% or ±.5 pF, whichever is greater		7 _{1mm/sec}								
Flexure Stresses	Q	Meets Initial Values (As Above)	V									
	Insulation Resistance	≥ Initial Value x 0.3	90 n									
		≥ 95% of each terminal should be covered	Dip device in eutectic									
Solde	rability	with fresh solder	for 5.0 ± 0.									
	Appearance	No defects, <25% leaching of either end terminal	101 0.0 ± 0.	0 0001100								
	Capacitance											
	Variation	\leq ±2.5% or ±.25 pF, whichever is greater	Dia de de la 1	-1-1								
Resistance to	Q	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± hours before measuring electrical properties									
Resistance to Solder Heat Thermal Shock	Insulation Resistance	Meets Initial Values (As Above)	riours before measuring	g electrical properties.								
	Dielectric	<u> </u>										
	Strength	Meets Initial Values (As Above)										
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes								
	Capacitance		·									
	Variation	\leq ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes								
	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes								
Snock	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes									
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 hours at room temperature									
	Appearance	No visual defects	_ 1 110010 01 100111 10111	00.000								
	Capacitance	≤ ±3.0% or ± .3 pF, whichever is greater										
	Variation	, ·	Charge device with to									
Load Life	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	test chamber set for 1000 hou	at 125°C ± 2°C								
Shock	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test cha room temperatu	re for 24 hours								
	Dielectric Strongth	Meets Initial Values (As Above)	before me	easuring.								
	Strength	No visual defects										
	Appearance Capacitance											
	Variation	\leq ±5.0% or ± .5 pF, whichever is greater	Store in a test chamb	er set at 85°C + 2°C/								
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	Store in a test chamber set at 85°C ± 2°C/85% ± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.									
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from cham room temperature	for 24 ± 2 hours								
	Dielectric Strength	Meets Initial Values (As Above)	before measuring.									

NP0/C0G Capacitance Range

PREFERRED SIZES ARE SHADED

SIZ	F		06	03			0805			1206											
	WVDC	40			100	40			100	40			100								
Cap 0.5	0R5	16	25	50	100	16	25	50	100	16	25	50	100								
(pF) 1.0	1R0																				
1.2	1R2																				
1.5	1R5																				
1.8	1R8																				
2.2	2R2																				
2.7	2R7																				
3.3	3R3																				
3.9	3R9																				
4.7	4R7																				
5.6	5R6																				
6.8	6R8																				
8.2	8R2																				
10	100																				
12	120																				
15	150																				
18	180																				
22	220																				
27	270																				
33	330																				
39	390																				
47	470																				
56	560																				
68	680																				
82	820																				
100	101																				
120	121																				
150	151																				
180	181																				
220	221																				
270	271																				
330	331																				
390	391																				
470	471																				
560	561																				
680	681																				
820	821																				
1000	102																				
1200	122																				
1500	152																				
	WVDC	16	25	50	100	16	25	50	100	16	25	50	100								
SIZE			0603				0805			1206											

X7R Specifications and Test Methods

Parame	ter/Test	X7R Specification Limits	Measuring	Conditions					
	perature Range	-55°C to +125°C	Temperature C						
Capac	itance	Within specified tolerance ≤ 10% for ≥ 50V DC rating	Freq.: 1.0 k						
Dissipation	on Factor	≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Voltage: 1.0Vrms ± .2V						
Insulation I	Resistance	100,000MΩ or 1000MΩ - μ F, whichever is less	Charge device with 120 ± 5 secs @ roo	om temp/humidity					
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.						
	Appearance	No defects	Deflectio						
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3						
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	V	THIN/SEC					
	Insulation Resistance	≥ Initial Value x 0.3	90 n	nm —					
Solderability		≥ 95% of each terminal should be covered with fresh solder	Dip device in eutection for 5.0 ± 0.						
	Appearance	No defects, <25% leaching of either end terminal							
	Capacitance Variation	≤ ±7.5%	Die device in outcetie	polder at 06000 for 60					
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2 hours before measuring electrical properties.						
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	Tiours before measuring	g electrical properties.					
	Dielectric Strength	Meets Initial Values (As Above)							
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes					
	Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes					
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes					
SHOCK	Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes					
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles ar 24 ± 2 hours at room						
	Appearance	No visual defects							
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 test chamber set						
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou	ırs (+48, -0)					
	Appearance Capacitance Variation Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor Insulation Resistance Variation Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor Insulation Resistance Capacitance Variation Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor Insulation Resistance Variation Dissipation Factor Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test ch at room temperatur						
	Dielectric	Meets Initial Values (As Above)	before me						
		No visual defects	Otomo in a toot of	ou and at 0000					
	Capacitance	≤ ±12.5%	Store in a test chamber 85% ± 5% relative hur	midity for 1000 hours					
Load Humidity	Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated						
	Insulation	≥ Initial Value x 0.3 (See Above)	Remove from cham room temperature	and humidity for					
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours before measuring.						

X7R Capacitance Range

PREFERRED SIZES ARE SHADED

SIZ	ZE		040)2	0603						0603 0805											1206									1210									1812					
	WVDC	16	25	50	10	16	25	50	100	200	10	16	25	50	100	200	250	10	16	25	50	100	200	250	500	10	16	25	50	100	200	250	500	50	100	200	50	100	200	250	25	50	100		
Cap 220	221	10	20	100	10	10	120	100	1100	7200	110	10	20	00	100	200	200	10	10	20	-00	100	200	200	000	10	10	20	100	100	200	200	000	-	100	200	-	100	200	1200	120	-	100		
pf 270	271																	\vdash				\vdash		Н			\vdash	\vdash	\vdash	\vdash	\vdash	\dashv		\vdash			\vdash			\vdash	\vdash	\vdash	_		
330	331	Н			\vdash						1																			\vdash				\vdash			Т			\vdash		т	_		
390	391	Н			\vdash				+		1															\vdash				T		\neg		\vdash			\vdash			\vdash	\vdash	\vdash	_		
470	471	Н			т				+		1																													\vdash	H	\vdash	_		
560	561	т			т				+		1							-								\vdash			1											\vdash	H	\vdash	_		
680	681	П			т						1							Т								\vdash						\neg		\vdash			Г			\vdash		\vdash	_		
820	821	Т			т						1																													\vdash		т	_		
1000	102				\vdash																											\neg								\vdash	T	т	_		
1200	122	Н			\vdash						1																										Т			\vdash		т	_		
1500	152	Н			Н		1		+																	\vdash						_								\vdash	H	\vdash	_		
1800	182	т			т				+																	\vdash						_								\vdash	H	\vdash	_		
2200	222																																							\vdash		\vdash	_		
2700	272																																	\vdash			\vdash			\vdash	\vdash	т	_		
3300	332	Н			\vdash																											\neg		\vdash			\vdash			\vdash		т	$\overline{}$		
3900	392																																							\vdash	t	\vdash	_		
4700	472	Н			Н				+																	\vdash						_								\vdash	\vdash	\vdash	_		
5600	562				✝	-	-	_	+																	Н			-	\vdash		\dashv	=	\vdash						\vdash	\vdash	\vdash	$\overline{}$		
6800	682	Н			\vdash	_	-	_	+																	Н			-			\neg	=	\vdash			\vdash			\vdash	-	\vdash	_		
8200	822	Н			\vdash	1	1	1	+																	\vdash						\neg	=	\vdash			\vdash			\vdash	-	\vdash	$\overline{}$		
cap 0.010	103	Н			Н	1	1	1	+	_																\vdash						_									-	\vdash	$\overline{}$		
uf 0.012	123				1																											\neg	=									т	_		
0.015	153	Н				-	+	-		+																			-	\vdash		\dashv										\vdash	_		
0.018	183	Н				-	-	1		+																			-	\vdash		\dashv	_									\vdash	_		
0.022	223	Н				-	-	_		+																			-	-		\neg	=				\vdash					\vdash	_		
0.027	273	Н				1	1	1		+																						\neg	=				\vdash					\vdash	_		
0.033	333	Н								1																						\neg	_				\vdash					\vdash	_		
0.039	393	т								+																						\neg	=									т	_		
0.047	473	╆	\vdash			+	+	-		+						\vdash								Н					-	\vdash		\dashv										\vdash	$\overline{}$		
0.056	563	Н				-	${}^{+}$	1		+						\vdash								Н					-	\vdash												\vdash	$\overline{}$		
0.068	683	т	\vdash	1						+														Н													Н				\vdash	\vdash	_		
0.082	823	$^{+}$	t	1						+						\vdash								Н													\vdash				\vdash	\vdash	_		
0.10	104	$^{+}$	T	1						+														Н											\vdash						\vdash	\vdash	_		
0.12	124	\vdash	\vdash	1					1	T														Н																					
0.15	154	t	\vdash	1			+	+	1	+														H								\dashv			\vdash										
0.13	224	+	+	1			+	+	+	+						\vdash								\vdash							\vdash	\dashv													
0.33	334	+	+	1	г		+	+	1	+						\vdash								\vdash							\vdash	\dashv													
0.47	474	+	+	+	\vdash	+	+	+	+	+														\vdash							\vdash	\dashv								\vdash					
0.56	564	+	+	+	\vdash	+	+	+	+	+														\vdash							\vdash	\dashv		\vdash						\vdash					
0.68	684	1	\vdash	+	\vdash	+	+	+	+	+														\vdash							\vdash	\dashv		\vdash						\vdash					
0.82	824	1	\vdash	+	\vdash	+	+	+	+	+												\vdash		\vdash								\dashv		\vdash						\vdash					
1.0		\vdash	\vdash	+	\vdash	+	+	+	+	+										\vdash		\vdash		\vdash								\dashv		\vdash						\vdash					
1.2		\vdash	\vdash	+	\vdash	+	+	+	+	+				\vdash								\vdash		\vdash							\vdash	\dashv		\vdash						\vdash					
1.5		+	+	+	\vdash	+	+	+	+	+	-											\vdash		\vdash		\vdash			+	\vdash	\vdash	\dashv		\vdash			\vdash			\vdash					
	WVDC	16	25	50	10	16	25	50	100	200	10	16	25	50	100	200	250	10	16	25	50	100	200	250	500	10	16	25	50	100	200	250	500	50	100	200	50	100	200	250	25	50	100		
					10	110				1200	10	10				1200	1200	10	10	20			200	200	JUU	10	10	120			200	200	JUU				50								
SIZ	ZE		040)2			0(603				0805					1206								1210								1	180	8		18	312	1	2220)				